

PROCEEDINGS OF SPIE

***Physical Chemistry of Semiconductor
Materials and Interfaces XX***

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Editors

1-5 August 2021
San Diego, California, United States

Sponsored and Published by
SPIE

Volume 11799

Proceedings of SPIE 0277-786X, V. 11799

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Author(s), "Title of Paper," in *Physical Chemistry of Semiconductor Materials and Interfaces XX*, edited by Andrew J. Musser, Derya Baran, Christian Nielsen, Daniel Congreve, Proc. of SPIE 11799, Seven-digit Article CID Number (DD/MM/YYYY); (DOI URL).

ISSN: 0277-786X

ISSN: 1996-756X (electronic)

ISBN: 9781510644366

ISBN: 9781510644373 (electronic)

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time)

SPIE.org

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Contents

FROM WEAK TO STRONG LIGHT-MATTER COUPLING

11799 06 Bi-ferrocene based molecular rectifier for nano-patch rectenna device [11799-5]

MECHANISM OF EXCITON FISSION AND FUSION

11799 0B Characterization of triplet separation and diffusion in amorphous pentacene films via ultrafast infrared spectroscopy [11799-12]

11799 0E Singlet fission in acene blends (Invited Paper) [11799-11]

LOW-DIMENSIONAL MATERIALS AND INTERFACES I

11799 0V Carrier dynamics and optical gain in InP-based quantum dots [11799-17]

ORGANIC SEMICONDUCTOR PHYSICS AND DEVICES I

11799 12 Investigating polaron dynamics in PM6:Y6 films for use in organic photovoltaics using time-resolved infrared spectroscopy [11799-28]

ORGANIC SEMICONDUCTOR PHYSICS AND DEVICES II

11799 17 Birefringence, dimensionality, and surface influences on organic hybrid electro-optic performance [11799-34]

11799 1A On the electronic structure of alternant conjugated organic radicals for light-emitting diode applications (Invited Paper) [11799-35]